

B L GALAXY ELECTRICAL

1A10F --- 1A18F

PHOTO FLASH RECTIFIER

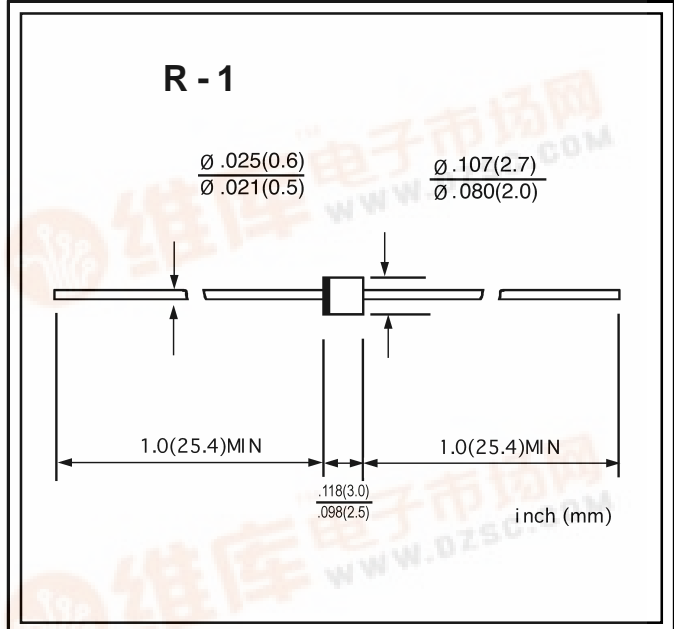
VOLTAGE RANGE: 1000 --- 1800 V
CURRENT: 1.0A

FEATURES

- ◇ Fast switching
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with alcohol, Isopropanol and similar solvents

MECHANICAL DATA

- ◇ Case: JEDEC R-1, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.007 ounces, 0.20 grams
- ◇ Mounting position: Any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate by 20%.

		1A10F	1A12F	1A14F	1A15F	1A16F	1A18F	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	1000	1200	1400	1500	1600	1800	V
Maximum RMS voltage	V_{RMS}	700	840	980	1050	1120	1260	V
Maximum DC blocking voltage	V_{DC}	1000	1200	1400	1500	1600	1800	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ C$	$I_{F(AV)}$	1.0						A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load $T_J=125^\circ C$	I_{FSM}	30.0						A
Maximum instantaneous forward voltage @ 1.0 A	V_F	1.3		1.8			V	
Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=100^\circ C$	I_R	5.0 100.0						μA
Maximum reverse recovery time (NOTE1)	t_{rr}	300						ns
Typical junction capacitance (NOTE2)	C_J	15						pF
Operating junction temperature range	T_J	-55 --- + 150						$^\circ C$
Storage temperature range	T_{STG}	-55 --- + 150						$^\circ C$

NOTE: 1. Reverse recovery test conditions: $I_F=0.5A, I_R=1.0A, I_{RR}=0.25A$.

2. Measured at 1MHz and applied reverse voltage of 4.0V.

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FIG.1 – FORWARD DERATING CURVE

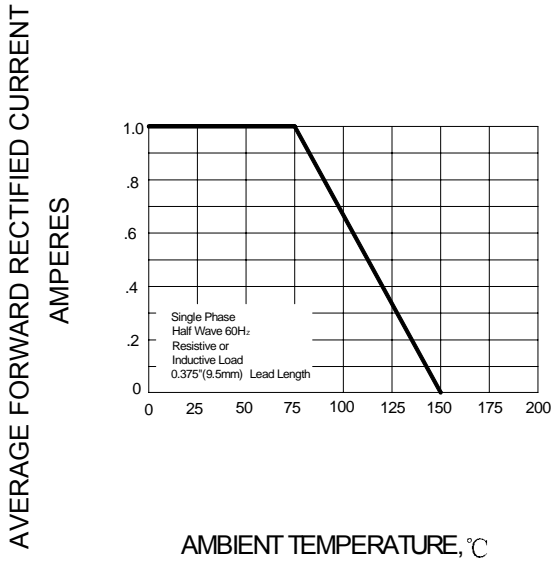


FIG.2 – PEAK FORWARD SURGE CURRENT

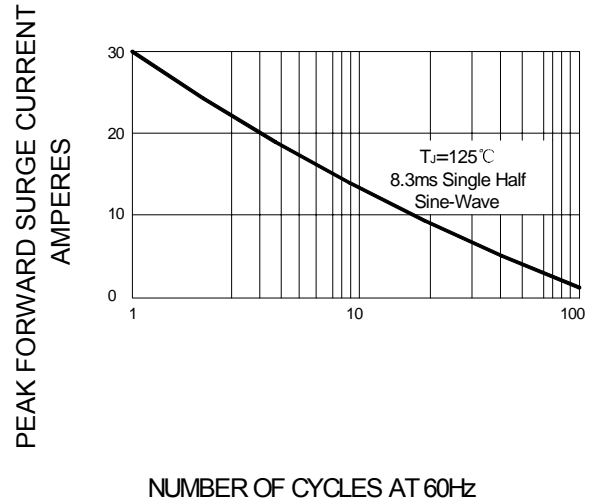
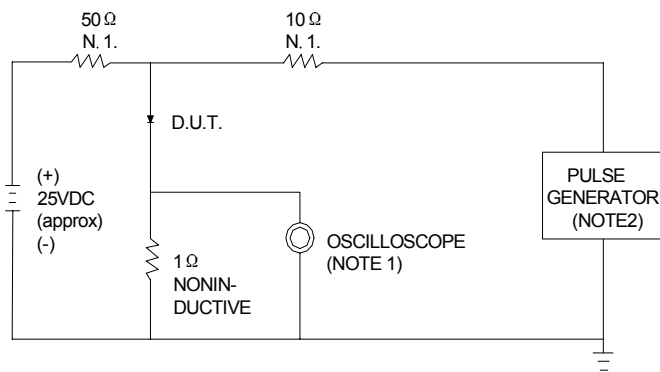


FIG.3 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = $1\text{M}\Omega$, 22pF.
2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50 Ω.

